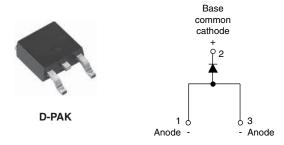


Vishay Semiconductors

## Surface Mountable Fast Soft Recovery Diode, 8 A



PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I <sub>F(AV)</sub>	8 A			
$V_{R}$	1000 V, 1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.3 V			
I <sub>FSM</sub>	110 A			
t <sub>rr</sub>	80 ns			
Diode variation	Single die			
Snap	0.6			

#### **FEATURES**

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition





ROHS\*
COMPLIANT
HALOGEN

FREE

#### **APPLICATIONS**

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions or conducted EMI should be met

#### **DESCRIPTION**

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Sinusoidal waveform	8	А		
V <sub>RRM</sub>		1000/1200	V		
I <sub>FSM</sub>		110	А		
V <sub>F</sub>	8 A, T <sub>J</sub> = 25 °C	1.3	V		
t <sub>rr</sub>	1 A, 100 A/µs	80	ns		
T <sub>J</sub>	Range	- 40 to 150	°C		

VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA			
VS-8EWF10S-M3	1000	1100	4			
VS-8EWF12S-M3	1200	1300	4			

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 96 °C, 180° conduction half sine wave	8	
Maximum peak one cycle	ı (1)	10 ms sine pulse, rated V <sub>RRM</sub> applied	93	Α
non-repetitive surge current	10 ms sine pulse, no voltage reapplied	110		
Maximum I <sup>2</sup> t for fusing I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	43	A <sup>2</sup> s	
	10 ms sine pulse, no voltage reapplied	61	A-S	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	432	A <sup>2</sup> √s

#### Note

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<sup>(1)</sup> Connecting one pin only

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	8 A, T <sub>J</sub> = 25 °C		1.3	V
Forward slope resistance	r <sub>t</sub>	- T <sub>J</sub> = 150 °C		25.6	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.93	V
Maximum reverse leakage current	1	$T_J = 25  ^{\circ}\text{C}$ $V_B = \text{Rated } V_{BBM}$	0.1	mA	
iviaximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 150 °C	VR = nateu VRRM	4	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> at 8 Apk	270	ns	I <sub>FM</sub>
Reverse recovery current	I <sub>rr</sub>	25 A/μs Τ <sub>J</sub> = 25 °C	4.2	А	$t_a \mid t_b$
Reverse recovery charge	Q <sub>rr</sub>		1	μC	di di Q
Snap factor	S		0.6		l" I"

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C	
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5	°C/W	
Typical thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> (1)		50	-C/W	
Soldering temperature	T <sub>S</sub>	For 10 s	240	°C	
Approximate weight			1	g	
Approximate weight			0.03	oz.	
Marking device		Case style D-PAK (TO-252AA)	8EWF10S		
iviai kiilig device		Case style D-1 AIX (10-232AA)	8EWF	12S	

#### Note

<sup>(2)</sup> When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



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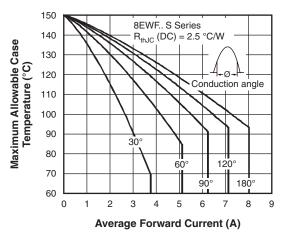


Fig. 1 - Current Rating Characteristics

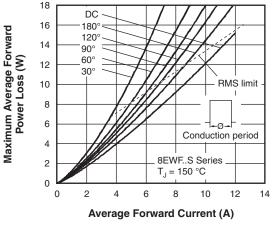


Fig. 4 - Forward Power Loss Characteristics

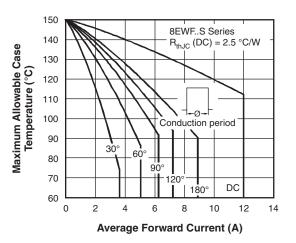


Fig. 2 - Current Rating Characteristics

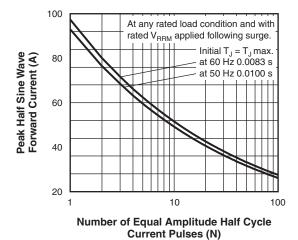


Fig. 5 - Maximum Non-Repetitive Surge Current

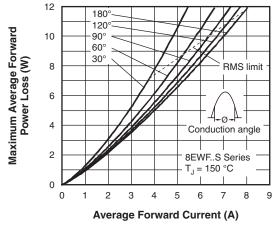


Fig. 3 - Forward Power Loss Characteristics

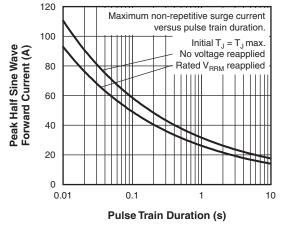


Fig. 6 - Maximum Non-Repetitive Surge Current

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### Surface Mountable Fast Soft Recovery Diode, 8 A



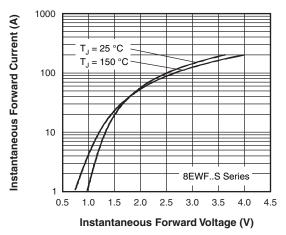


Fig. 7 - Forward Voltage Drop Characteristics

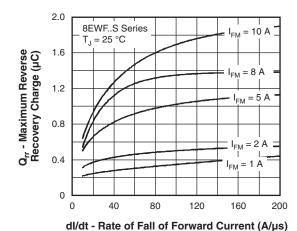


Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C

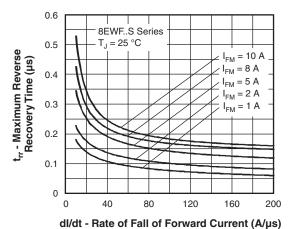


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

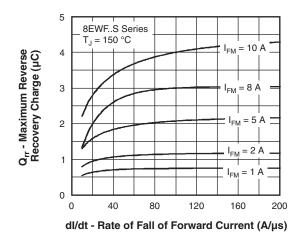


Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C

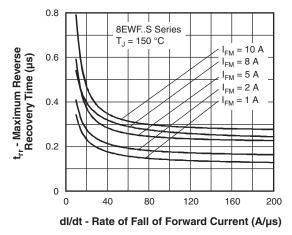
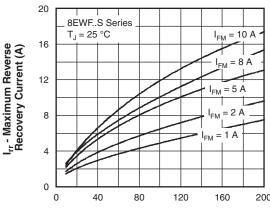


Fig. 9 - Recovery Time Characteristics, T<sub>J</sub> = 150 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C



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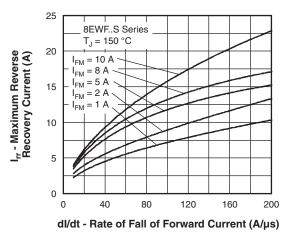


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

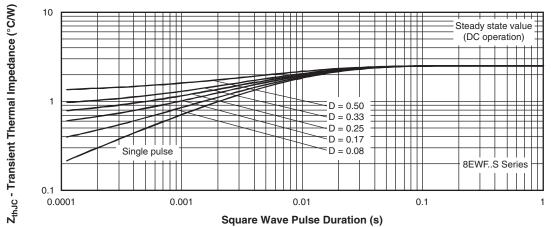


Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics

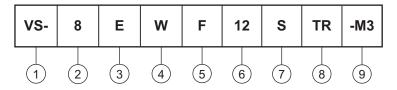
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#### **ORDERING INFORMATION TABLE**

Device code



- Vishay Semiconductors product
- Current rating (8 = 8 A)
- Circuit configuration:

E = Single diode

| 4 | Package:

W = D-PAK

5 Type of silicon:

F = Fast soft recovery rectifier

- 10 = 1000 V Voltage code x 100 = V<sub>RRM</sub> 12 = 1200 V
- S = Surface mountable
- TR = Tape and reel
  - TRR = Tape and reel (right oriented)
  - TRL = Tape and reel (left oriented)
- 9 Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-8EWF10S-M3	75	3000	Antistatic plastic tubes		
VS-8EWF10STR-M3	2000	2000	13" diameter reel		
VS-8EWF10STRL-M3	3000	3000	13" diameter reel		
VS-8EWF10STRR-M3	3000	3000	13" diameter reel		
VS-8EWF12S-M3	75	3000	Antistatic plastic tubes		
VS-8EWF12STR-M3	2000	2000	13" diameter reel		
VS-8EWF12STRL-M3	3000	3000	13" diameter reel		
VS-8EWF12STRR-M3	3000	3000	13" diameter reel		

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95016			
Part marking information	www.vishay.com/doc?95176		
Packaging information	www.vishay.com/doc?95033		





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